

# Possible New Superconductors in Al-B and RE-Si<sub>5</sub> using High Pressure - High Temperature



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AFOSR MURI "SEARCH FOR NEW SUPERCONDUCTORS FOR ENERGY AND POWER APPLICATIONS"



## ① Introduction:

- ❖ Search for SC in the **RESi<sub>5</sub>** (**CeSi<sub>5</sub>**, **PrSi<sub>5</sub>** & **NdSi<sub>5</sub>**) and **Al-B** systems .

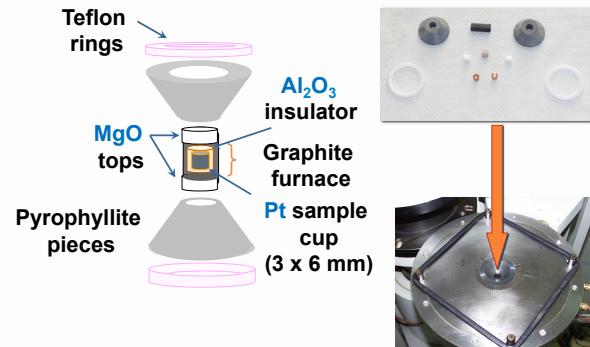
- ❖ **LaSi<sub>5</sub>** showed new SC. ( $T_c=11.5$  K), S. Yamanaka *et al.*. *J. Solid State Chem.*, 182, (2009).

- ❖ **Al<sub>0.67</sub>B<sub>2</sub>** : the **MgB<sub>2</sub>** analog.

- ❖ Synthesize **AIB<sub>2</sub>** off stoichiometry.

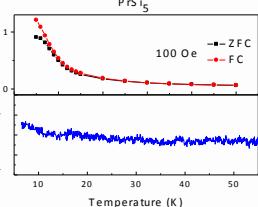
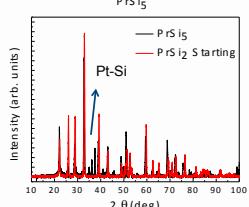
	Arc Melting	HP-HT	Thin Film
La-Si-C	✓		✓
La-Si-B	✓		
Ce-Si-C	✓		
Ce-Si-C	✓		
Pr-Si-C	✓		
Pr-Si-B	✓		
Nd-Si-C		✓	
Nd-Si-B		✓	
Eu-Si-C			
Eu-Si-B			
Gd-Si-C		✓	
Gd-Si-B		✓	
CeSi <sub>5</sub>		✓	
PrSi <sub>5</sub>		✓	
NdPr <sub>5</sub>		✓	
Al-B	✓	✓	✓
La-Ba-Fe-Si	✓	✓	✓
V-Si-C		✓	

## ② HIGH PRESSURE-HIGH TEMP (HP-HT)



❖ Up to 80 Kbar and 1400°C.

## ③ CeSi<sub>5</sub>, PrSi<sub>5</sub> and NdSi<sub>5</sub>

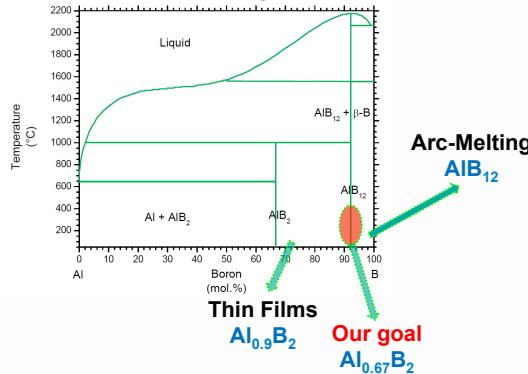


- ❖ No SC.
- ❖ No formation of RESi<sub>5</sub> compounds.

## ④ Al<sub>0.67</sub>B<sub>2</sub> : the MgB<sub>2</sub> analog

Al<sub>0.67</sub>B<sub>2</sub> off stoichiometry:

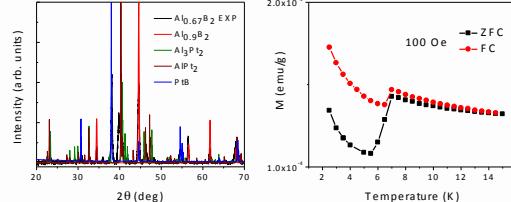
HP-HT, Arc-Melting, and thin films.



## ⑤ Al<sub>0.67</sub>B<sub>2</sub>



SC at 7 K



- ❖ Intermetallic compounds: capsule reaction.
- ❖ None of them could explain the SC.

## ⑥ Conclusions:

- ❖ HP-HT :unique technique for searching for new SC.
- ❖ **RESi<sub>5</sub>** using HP-HT : NO SC.
- ❖ **AIB<sub>2</sub>** shows promising results: the origin of the SC should be clarified.

## Future Work:

- ❖ Prevent capsule reaction.
- ❖ New materials, different parameters.
- ❖ Explore intensively the **AIB<sub>2</sub>** system in thin film form taking advantage of the MFMMS.